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Patent
Case No.: 58994US002



IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

First Named Inventor: LEE, TZU-CHEN
Application No.: 10/809135 Group Art Unit: 2811
Filed: March 25, 2004 Examiner: VU, Hung K.
Title: ORGANIC SCHOTTKY DIODE

INFORMATION DISCLOSURE STATEMENT

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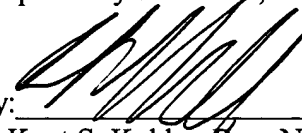
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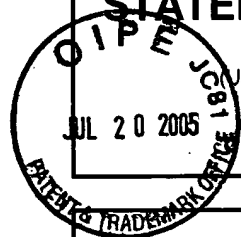
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Application Number**10/809135****Filing Date****March 25, 2004****First Named Inventor****Lee, Tzu-Chen****Art Unit****2811****Examiner Name****VU, Hung K.****Attorney Case Number****58994US002****U.S. Patent Documents**

Exam. Init.*	Cite No.	Document Number	Publication Date or Issue Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
		Doc. Number-(Kind Code if Known)			
	A1	US-			
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OTHER DOCUMENTS

Exam. Init.*	Cite No.	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	Translation (Check if yes)
	C1	PFEIFFER, "Doped Organic Semiconductors: Physics and Application in Light Emitting Diodes", Organic Electronics, (2003), pp. 89-103, Vol. 4, Elsevier B. V.	
	C2	BLOCHWITZ, "Non-Polymeric OLEDs With a Doped Amorphous Hole Transport Layer and Operating Voltages Down to 3.2 V to Achieve 100 cd/m ² ", Synthetic Metals, (2002), pp. 169-173, Vol. 127, Elsevier Science B. V.	
	C3	ROMAN, "Polymer Diodes With High Rectification", Applied Physics Letters, (November 29, 1999), pp. 3557-3559, Vol. 75, No. 22, American Institute of Physics	
	C4	OUYANG, "On the Mechanism of Conductivity Enhancement in Poly(3,4-ethylenedioxythiophene):Poly(styrene sulfonate) Film Through Solvent Treatment", Polymer, (2004), pp. 8443-8450, Vol. 45	
	C5	IONESCU-ZANETTI, "Semiconductive Polymer Blends: Correlating Structure With Transport Properties at the Nanoscale", Advanced Materials, (March 5, 2004), pp. 385-389, Vol. 16, No. 5, Wiley-VCH Verlag GmbH & Co. KGaA, Weinheim	

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